



Spec No.: DS30-2000-359 Effective Date: 11/14/2000

Revision: -

LITE-ON DCC

RELEASE

BNS-OD-FC001/A4

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FEATURES

- *2.0 inch (50.8 mm) DIGIT HEIGHT.
- *LOW POWER REQUIREMENT.
- *EXCELLENT CHARACTERS AND APPEARANCE.
- *HIGH CONTRAST.
- *HIGH BRIGHTNESS.
- *WIDE VIEWING ANGLE.
- *4X4 ARRAY WITH X-Y SELECT.
- *STACKABLE VERTICALLY AND HORIZONTALLY.

DESCRIPTION

The LTP-2344G is 2.0 inch (50.8 mm) matrix height 4x4 dot matrix display. This device utilizes green LED chips, which are made from GaP on a GaP substrate, and has a gray face and white dots.

DEVICE

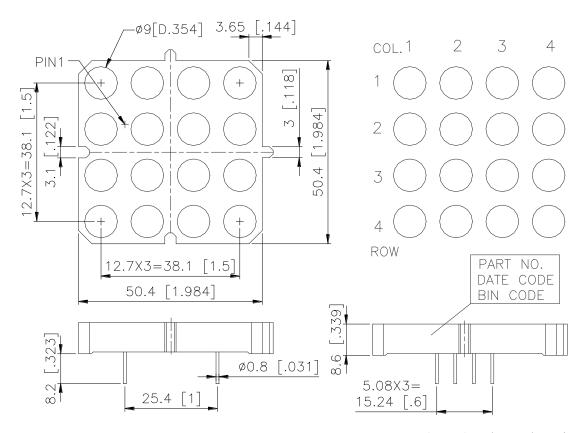
PART NO.	DESCRIPTION				
GREEN	ANODE ROW				
LTP-2344G	CATHODE COLUMN				

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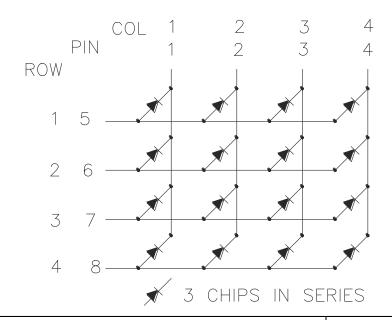
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PACKAGE DIMENSIONS



NOTES: All dimensions are in millimeters. Tolerances are \pm 0.25 mm (0.01") unless otherwise noted.

INTERNAL CIRCUIT DIAGRAM



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PIN CONNECTION

No.	CONNECTION				
1	CATHODE COLUMN 1				
2	CATHODE COLUMN 2				
3	CATHODE COLUMN 3				
4	CATHODE COLUMN 4				
5	ANODE ROW 1				
6	ANODE ROW 2				
7	ANODE ROW 3				
8	ANODE ROW 4				

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ABSOLUTE MAXIMUM RATING AT Ta=25°C

PARAMETER	MAXIMUM RATING	UNIT		
Average Power Dissipation Per Dot	96	mW		
Peak Forward Current Per Dot	90	mA		
Average Forward Current Per Dot	11	mA		
Derating Linear From 25°C Per Dot	0.15	mA/°C		
Reverse Voltage Per Segment	15	V		
Operating Temperature Range	-35°C to +85°C			
Storage Temperature Range	-35°C to +85°C			
Solder Temperature: max 260°C for ma	ax 3sec at 1.6mm[1/16inch] below sea	ting plane.		

ELECTRICAL / OPTICAL CHARACTERISTICS AT Ta=25°C

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Average Luminous Intensity	Iv	5.0	11.0		mcd	I _P =80mA 1/16DUTY
Peak Emission Wavelength	λр		565		nm	I _F =20mA
Spectral Line Half-Width	Δλ		30		nm	I _F =20mA
Dominant Wavelength	λd		569		nm	I _F =20mA
Forward Voltage Per Chip	VF		6.3	7.8	V	I _F =20mA
			9.0	11.1		I _F =80mA
Reverse Current Per Chip	Ir			100	μΑ	V _R =15V
Luminous Intensity Matching Ratio	Iv-m			2:1		IP=80mA 1/16DUTY

Note: Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (Commision Internationale De L' Eclariage) eye-response curve.

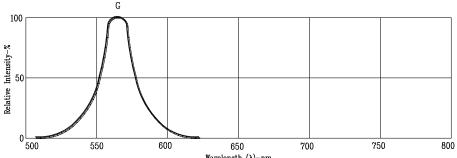
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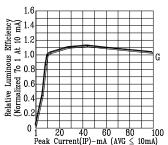
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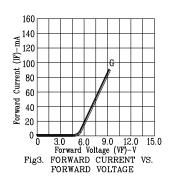
TYPICAL ELECTRICAL / OPTICAL CHARACTERISTIC CURVES

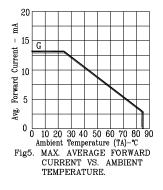
(25°C Ambient Temperature Unless Otherwise Noted)





-1 ZU 40 60 80 100
Peak Current(IP)-mA (AVG ≦ 10mA)
Fig2. RELATIVE LUMINOUS EFFICIENCY
(LUMINOUS INTENSITY PER UNIT
CURRENT) VS. PEAK CURRENT
(REFRESH RATE 1KHz)





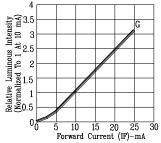
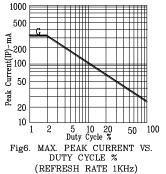


Fig4. RELATIVE LUMINOUS INTENSITY VS. FORWARD CURRENT



NOTE: G=GREEN

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